

10/524186

Docket No. 12406-107US1 Sheet 1 of 1

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 12406-107US1	Application No. To Be Assigned
Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Christian Karnutsch et al.	
		Filing Date Herewith 2/8/05	Group Art Unit 2113

U.S. Patent Documents

Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
MDH	AA	3,745,423	07/10/1973	Kasano, Hiroyuki	—	—	
↓	AB	4,218,270	08/19/1980	Hasegawa et al.	—	—	
↓	AC	5,233,204	08/03/1993	Fletcher et al.	—	—	
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
MDH	AL	WO 02/09242	01/31/2002	WIPO	—	—		
	AM							
	AN							
	AO							
	AP							

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
MDH	AQ	Modak, P. et al., "InAlGaP Microcavity LEDs on Ge-substrates", <i>Journal of Crystal Growth</i> , Vol. 221, pp. 668-673, 2000.
↓	AR	Wang, XL. Et al., "Si and Zn Doping of GaP Grown by OMVPE Using Tertiarybutylphosphine", <i>Journal of Crystal Growth</i> , Vol. 158, pp. 49-52, 1996.
	AS	
	AT	

Examiner Signature: <i>Monica D. Harris</i>	Date Considered: 3/14/06
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

Substitute Disclosure Form (PTO-1449)